AN7125

Dual Channel BTL Power Amplifier

■ Overview

AN7125 is a monolithic integrated circuit designed for 13.5 W (12 V,4 Ω) output audio power amplifier.It is a dual channel BTL IC suitable for stereo operation in radio cassette and TV application.

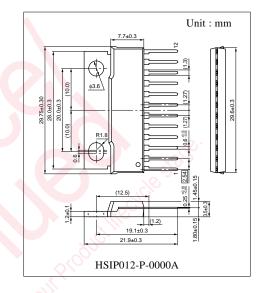
■ Features

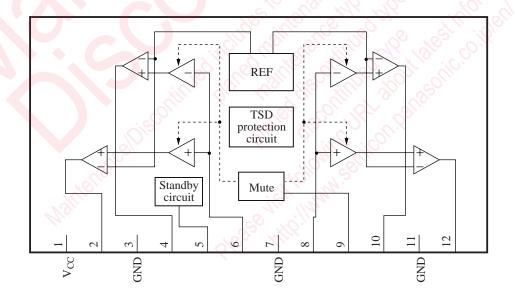
- Built-in muting pin
- Built-in stand by pin
- Built-in thermal shutdown protection circuit
- Built-in current limiting circuit
- High power : $(13.5 \text{ W}/12 \text{ V}/4 \Omega)$ $(13.0 \text{ W}/15 \text{ V}/8 \Omega)$
- Few external components
- Operating voltage range 6 V ~ 18 V (12 V typ.)

■ Applications

• Radio-cassette

■ Block Diagram





■ Pin Descriptions

Pin No.	Description	Pin No.	Description
1	V_{CC}	7	Pre GND
2	ch.1 + ve Phase Output	8	ch.2 Input
3	ch.1 Output GND	9	Mute
4	ch.1-ve Phase Output	10	ch.2 –ve Phase Output
5	Standby	11	ch.2 Output GND
6	ch.1 Input	12	ch.2 +ve Phase Output

■ Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Supply voltage *1	V _{CC}	24	V
Supply current	I _{CC}	6.0	A
Power dissipation *2	P_{D}	38.5	W
Operating ambient temperature	T _{opr}	-25 to +75	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note) *1: Without input signal, V_{CC} is up to 24 V

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{CC}	6.0 to 18.0	v

■ Electrical Caracteristics at $V_{CC} = 12 \text{ V}$, $R_L = 4 \Omega$, freq. = 1 kHz, 2 channel outputs, $T_a = 25 \text{ }^{\circ}\text{C}$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Quiescent circuit current	I_{CQ}	$V_{IN} = 0 \text{ mV}$	_	100	210	mA
Output noise voltage *1	V _{NO}	$V_{IN} = 0 \text{ mV}, R_G = 6.2 \text{ k}\Omega$	_	0.27	0.5	mVrms
Voltage gain	G _{VC}	$V_{IN} = 20 \text{ mV}$	38	40	42	dB
Total harmonic distortion *2	THD	$V_{IN} = 20 \text{ mV}$	_	0.07	0.4	%
Maximum output power	Po	THD = 10 %	10	12	_	W
Channel balance	СВ	$V_{IN} = 20 \text{ mV}$	-1	0	1	dB
Channel crosstalk *2	CT	$V_{IN} = 20 \text{ mV}, R_G = 6.2 \text{ k}\Omega$	55	70	_	dB
Output offset voltage	V _{OFF}	$R_G = 6.2 \text{ k}\Omega$	-350	0	350	mV
Ripple rejection *1	RR	$V_R = 1 \ V_{rms}, f_R = 120 \ Hz, R_G = 6.2 \ k\Omega$	50	60	_	dB
Standby current	I_{STB}	$V_{IN} = 0 \text{ mV}$	_	1	10	μА
Muting effects *2	MT	$V_{IN} = 20 \text{ mV}$	70	80		dB

Note) *1: With a filter band 20 Hz to 20 kHz(12 dB/OCT)used.

2 Panasonic

^{*2:} $T_a = 75$ °C.

^{*2}: With a filter band 400 Hz to 30 kHz used.

■ Terminal Equivalent Circuit

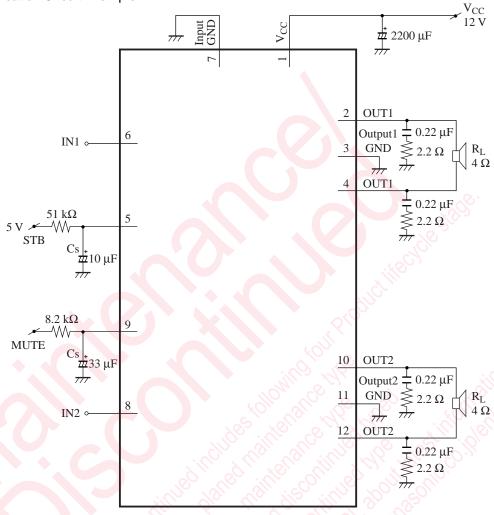
Pin No.	Equivalent Circuit	Function	Status
1	_	V _{CC} : V _{CC} input	typ.: 12 V
2	プリアンプ Pin2	ch.1 O/P: ch.1 positive phase output pin.	V _{CC} /2
3	ドライバ回路	ch.1 Power GND : ch.1 output power ground pin.	0 V
4	600 Ω 30 kΩ (3) V _{CC} /2	ch.1 O/P : ch.1 inverse phase output pin.	$V_{\rm CC}/2$
5	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Standby: This is the standby control pin. STB off > 3.5 V STB on = 0 V/GND	V _{TH} = 2.8 V
6	200 Ω Pin6,8 30 kΩ	ch.1 Input: This is the amplifier input pin.	0 V
7		Pre GND : Input ground pin.	0 V

3

■ Terminal Equivalent Circuit(continued)

Pin No.	Equivalent Circuit	Function	Status
8	200 Ω 400 Ω Pin6,8 30 kΩ	ch.2 Input: This is the amplifier input pin.	0 V
9	9 3.2 kΩ 3.6 kΩ 7 20 kΩ	Mute: Mute input pin. Mute on > 2.5 V Mute off = 0 V	V _{TH} = 1.5 V
10	プリアンプ「ドライバ回路」	ch.2 Output : ch.2 inverse phase output pin	V _{CC} /2
11	Pin10 12	ch.2 Power GND : ch.2 output power ground	0 V
12	600 Ω 30 kΩ (11) V _{CC} /2	ch.2 Output : ch.2 positive phase output pin	V _{CC} /2

■ Application Circuit Example



	STB 'Off'	5 V
V	STB 'On'	0 V
	Mute 'Off'	0 V
	Mute 'On'	5 V

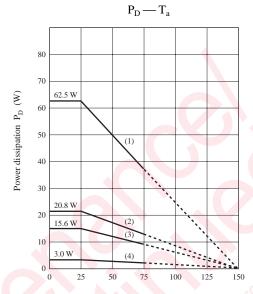
■ Application 's Precautions

- 1. External heatsink is needed when used. External heatsink should be fixed to the chassis.
- 2. Fin of the IC can be connected to GND.
- 3. Please prevent output to V_{CC} short and output to GND short.
- 4. The temperature protection circuit will operate at Tj around 150 °C.
 However, if temperature decrease, the protection circuit will automatically be decreased and resume normal operation.

Panasonic 5

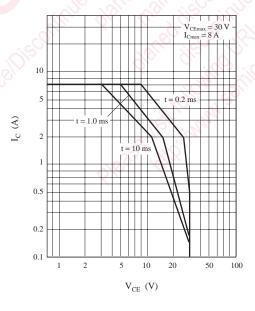
■ Technical Information

• HSIP012-P-0000A



- Ambient temperature T_a (°C)
- 1. $T_C = T_a$,62.5 W ($\theta_{j-c} = 2$ °C/W) 2. 20.83 W ($\theta f = 4.0$ °C/W) With a 100 cm² X 3 mm Al heat sink (black colour coated) or a 200 cm² X 2 mm Al heat sink (not lacquered)
- 3. 15.63 W ($\theta_f = 6.0 \, ^{\circ}\text{C/W}$) With a 100 cm² X 2 mm Al heat sink (not lacquered)
- 4. 3.0 W at $T_a = 25$ °C($\theta_{j-a} = 42$ °C/W) Without heat sink

Area of safe operation



Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products, and no license is granted under any intellectual property right or other right owned by our company or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.
- (3) The products described in this book are intended to be used for standard applications or general electronic equipment (such as office equipment, communications equipment, measuring instruments and household appliances).

 Consult our sales staff in advance for information on the following applications:
 - Special applications (such as for airplanes, aerospace, automobiles, traffic control equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.
 - Any applications other than the standard applications intended.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
- Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of Matsushita Electric Industrial Co., Ltd.